MOSFET – Power, Dual, N-Channel, for 1-Cell Lithium-ion Battery Protection

12 V, 2.75 mΩ, 33 A

EFC2K102ANUZ

Overview

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

Features

- 2.5 V Drive
- Common–Drain type
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

Applications

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

Specifications

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Parameter	Symbol	Value	Unit
Source to Source Voltage	V _{SSS}	12	V
Gate to Source Voltage	V _{GSS}	±8	V
Source Current (DC)	IS	33	А
Source Current (Pulse) PW \leq 10 μ s, duty cycle \leq 1%	I _{SP}	135	A
Total Dissipation (Note 1)	PT	3.1	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{ heta JA}$	40.3	°C/W

1. Surface mounted on ceramic substrate (5000 $\text{mm}^2 \times 0.8$ mm).

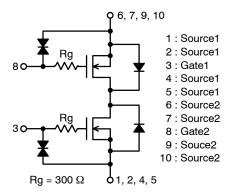


ON Semiconductor®

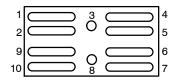
www.onsemi.com

V _{SSS}	R _{SS(on)} Max	I _{S Max}
12 V	$2.75~\mathrm{m}\Omega$ @ $4.5~\mathrm{V}$	33 A
	$2.85\ \text{m}\Omega\ @\ 3.8\ \text{V}$	
	$3.95~\mathrm{m}\Omega$ @ $3.1~\mathrm{V}$	
	6.1 mΩ @ 2.5 V	

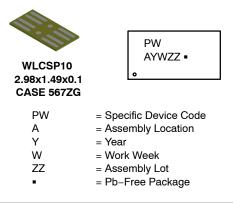
ELECTRICAL CONNECTION N-Channel



PIN ASSIGNMENT



MARKING DIAGRAM



ORDERING INFORMATION

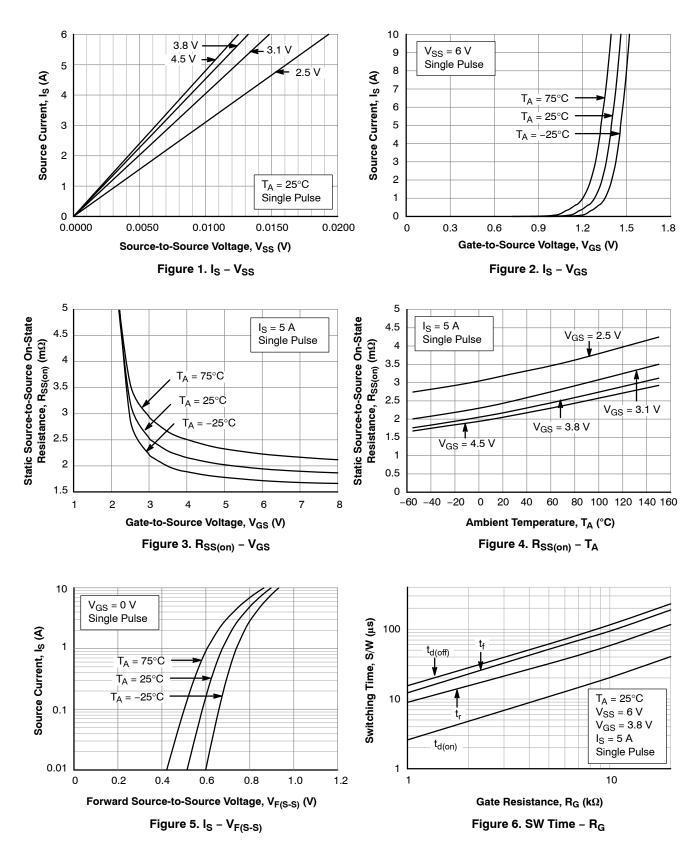
See detailed ordering and shipping information on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25° C)

				Value			
Parameter	Symbol	Condition	s	Min	Тур	Мах	Unit
Source to Source Breakdown Voltage	V(_{BR}) _{SSS}	I _S = 1 mA, V _{GS} = 0 V	Test Circuit 1	12	-	-	V
Zero-Gate Voltage Source Current	I _{SSS}	$V_{SS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	Test Circuit 1	-	-	1	μA
Gate to Source Leakage Current	I _{GSS}	V_{GS} = ±8 V, V_{SS} = 0 V	Test Circuit 2	-	-	±1	μA
Gate Threshold Voltage	V _{GS(th)}	V _{SS} = 6 V, I _S = 1 mA	Test Circuit 3	0.4	-	1.3	V
Static Source to Source On-State Resistance	R _{SS(on)}	I _S = 5 A, V _{GS} = 4.5 V	Test Circuit 4	1.55	2.10	2.75	mΩ
		I _S = 5 A, V _{GS} = 3.8 V	Test Circuit 4	1.60	2.20	2.85	mΩ
		I _S = 5 A, V _{GS} = 3.1 V	Test Circuit 4	1.65	2.40	3.95	mΩ
		I _S = 5 A, V _{GS} = 2.5 V	Test Circuit 4	1.90	3.10	6.10	mΩ
Turn-ON Delay Time	t _{d(on)}	V_{SS} = 6 V, V_{GS} = 3.8 V, I_S = 5 A, R_g = 10 $k\Omega$ Test Circuit 5		-	20	-	μs
Rise Time	t _r			-	58	-	μs
Turn-OFF Delay Time	t _{d(off)}			-	115	-	μs
Fall Time	t _f			-	94	-	μs
Total Gate Charge	Qg	$V_{SS} = 6 V, V_{GS} = 3.8 V, I_{S} = 5 A$		-	42	-	nC
Forward Source to Source Voltage	V _{F(S-S)}	$I_S = 3 \text{ A}, V_{GS} = 0 \text{ V}$ Test Circuit 7		-	0.75	1.20	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (Continued)

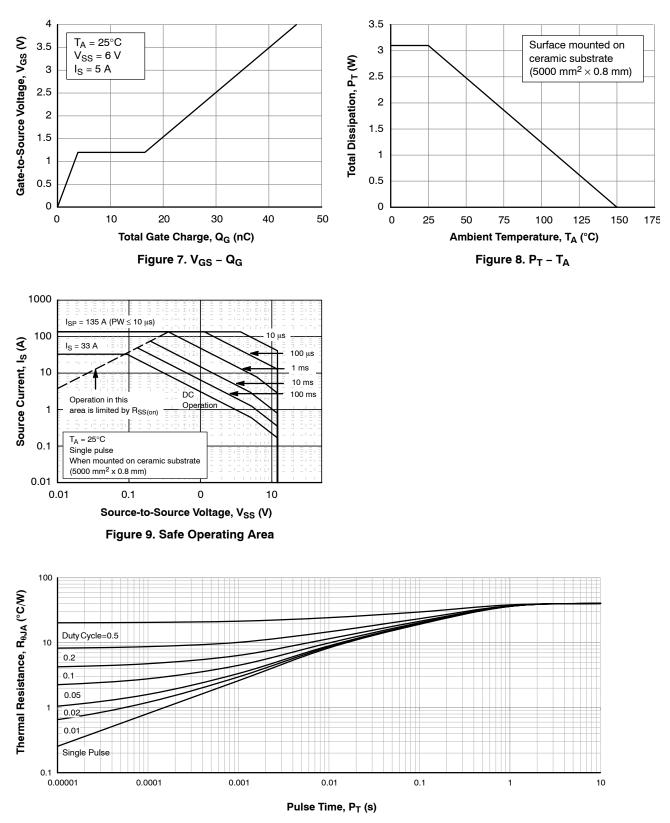
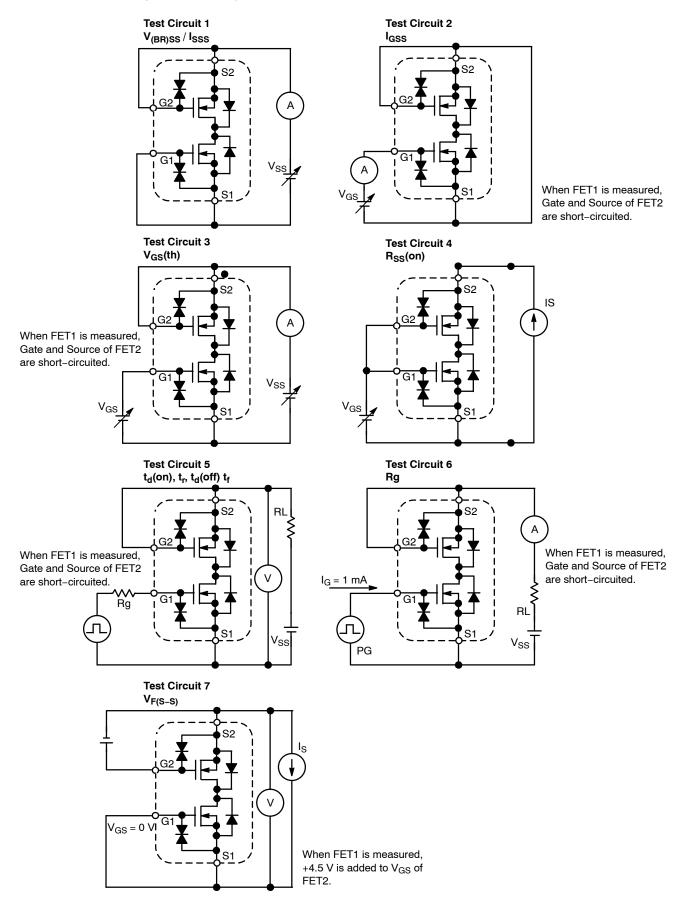


Figure 10. Thermal Response

Test Circuits are Example of Measuring FET1 Side



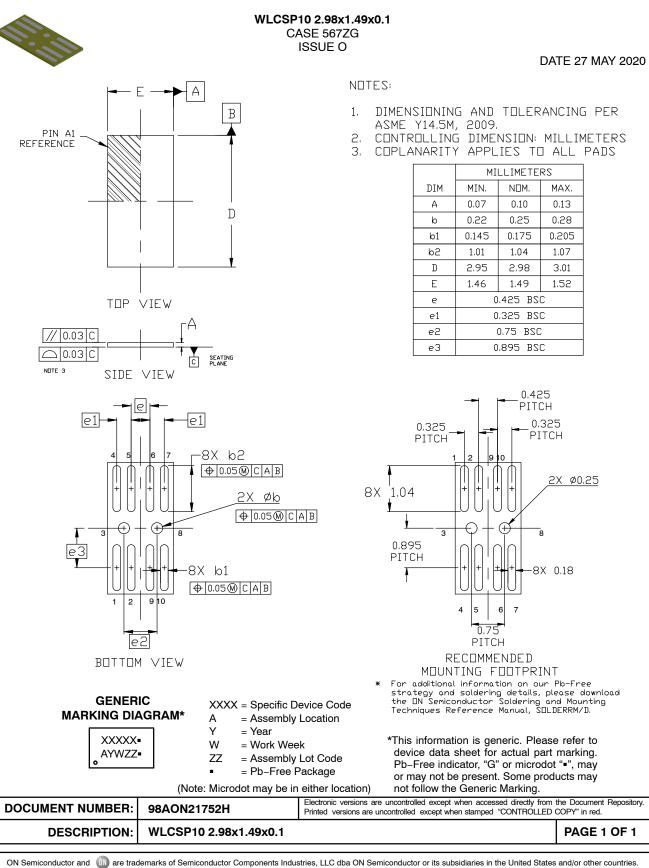
ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing) †
EFC2K102ANUZTDG	PW	WLCSP10, 2.98x1.49x0.1 (Pb-Free/Halogen Free)	5,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: Since the EFC2K102ANUZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.





ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative